Dual 4-input NAND gate Rev. 5 — 27 March 2019

Product data sheet

1. General description

The 74HC20; 74HCT20 is a dual 4-input NAND gate. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

2. Features and benefits

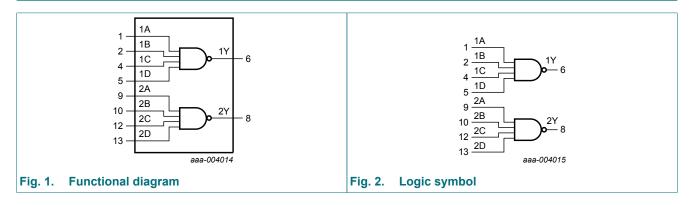
- Complies with JEDEC standard JESD7A
- Low-power dissipation
- Input levels:
 - For 74HC20: CMOS level
 - For 74HCT20: TTL level
- ESD protection:
 - HBM JESD22-A114F exceeds 2 000 V
 - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +80 °C and from -40 °C to +125 °C.

3. Ordering information

Table 1. Ordering information

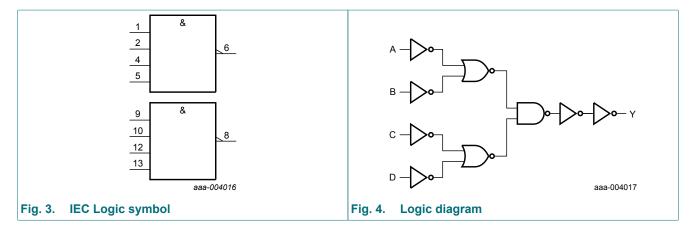
Type number	Package	Package									
	Temperature range	Name	Description	Version							
74HC20D	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads;	SOT108-1							
74HCT20D			body width 3.9 mm								
74HC20DB	-40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads;	SOT337-1							
74HCT20DB			body width 5.3 mm								
74HC20PW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1							

4. Functional diagram

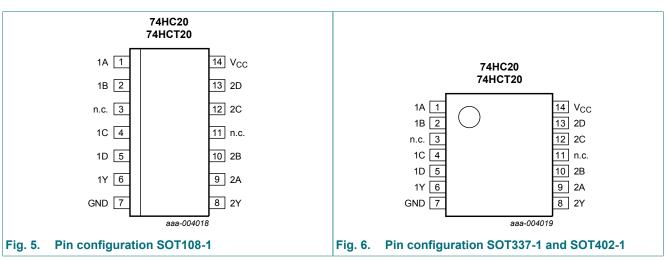


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Dual 4-input NAND gate



5. Pinning information



5.1. Pinning

5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 1B, 1C, 1D	1, 2, 4, 5	data input
n.c.	3, 11	not connected
1Y	6	data output
GND	7	ground (0 V)
2Y	8	data output
2A, 2B, 2C, 2D	9, 10, 12, 13	data input
V _{CC}	14	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Input	nput				
nA	nB	nC	nD	nY	
L	Х	Х	Х	Н	
Х	L	Х	Х	Н	
Х	Х	L	Х	Н	
Х	Х	Х	L	Н	
Н	Н	Н	Н	L	

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I _{ОК}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	[1]	-	±20	mA
I _O	output current	$-0.5 V < V_O < V_{CC} + 0.5 V$		-	±25	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	SO14, and (T)SSOP14 packages	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO14 package: Ptot derates linearly with 8 mW/K above 70 °C.

For (T)SSOP14 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	l Parameter Conditions		74HC20			74HCT20			Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Мах	Min	Max	1
74HC20						1		1	1	1
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2 mA; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	V _I = V _{IH} or V _{IL}								
	output voltage	I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	_	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	2	-	20	-	40	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT2	0									-
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 5.2 mA	-	0.15	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 5.5 V	-	-	2	-	20	-	40	μA

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Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
ΔI _{CC}		per input pin; $V_I = V_{CC} - 2.1 V$; $I_O = 0 A$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V		30	108	-	135	-	147	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

 $GND = 0 V; C_L = 50 pF;$ for test circuit see Fig. 8.

Symbol Parameter		Conditions			25 °C		-40 °C to	• +125 °C	Unit
				Min	Тур	Мах	Max (85 °C)	Max (125 °C)	
74HC20									
t _{pd}	propagation delay	nA, nB, nC or nD to nY; see Fig. 7	1]						
		V _{CC} = 2.0 V		-	28	90	115	135	ns
		V _{CC} = 4.5 V		-	10	18	23	27	ns
		V _{CC} = 6.0 V		-	8	15	20	23	ns
		V _{CC} = 5.0 V; C _L = 15 pF		-	8	-	-	-	ns
t _t	transition time	nY; see Fig. 7 [2]						
		V _{CC} = 2.0 V		-	19	75	95	110	ns
		V _{CC} = 4.5 V		-	7	15	19	22	ns
		V _{CC} = 6.0 V		-	6	13	16	19	ns
C _{PD}	power dissipation capacitance	per package; V_I = GND to V_{CC} [3]	-	22	-	-	-	pF
74HCT2	D	-			I	I	1	1	
t _{pd}	propagation delay	nA, nB, nC or nD to nY; see Fig. 7	1]						
		V _{CC} = 4.5 V		-	16	28	35	42	ns
		V _{CC} = 5.0 V; C _L = 15 pF		-	13	-	-	-	ns
tt	transition time	nY; V _{CC} = 4.5 V; see <u>Fig. 7</u> [2]	-	7	15	19	22	ns
C _{PD}	power dissipation capacitance	per package; V _I = GND to V _{CC} - 1.5 V [3]	-	17	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} . [2] t_t is the same as t_{THL} and t_{TLH} . [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of outputs.

10.1. Waveform and test circuit

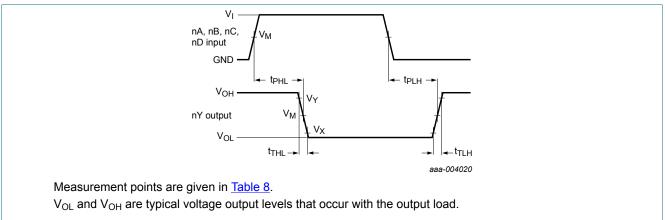
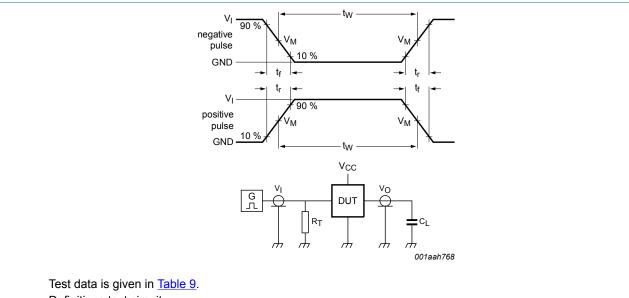


Fig. 7. Waveforms showing the input (nA, nB, nC, nD) to output (nY) propagation delays and the output transition times

Table	8.	Measurement	points
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Туре	Input	Output				
	V _M	V _M	V _X	V _Y		
74HC20	0.5V _{CC}	0.5V _{CC}	0.1V _{CC}	0.9V _{CC}		
74HCT20	1.3 V	1.3 V	0.1V _{CC}	0.9V _{CC}		



Definitions test circuit:

 R_T = termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = load capacitance including jig and probe capacitance.

Fig. 8. Test circuit for measuring switching times

Table 9. Test data

Туре	Input Lo		Load	Test
	VI	t _r , t _f	CL	
74HC20	V _{CC}	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}
74HCT20	3.0 V	6.0 ns	15 pF, 50 pF	t _{PLH} , t _{PHL}

74HC_HCT20

11. Package outline

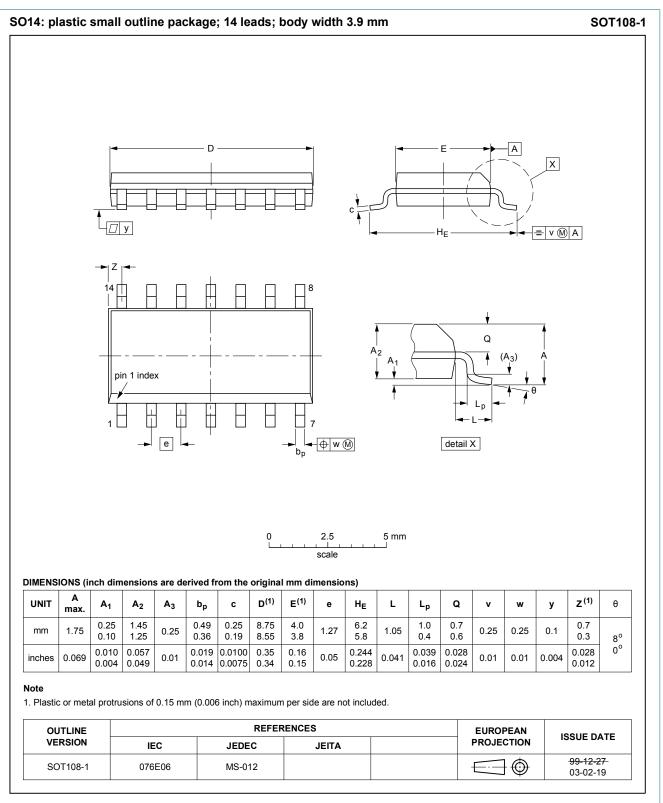
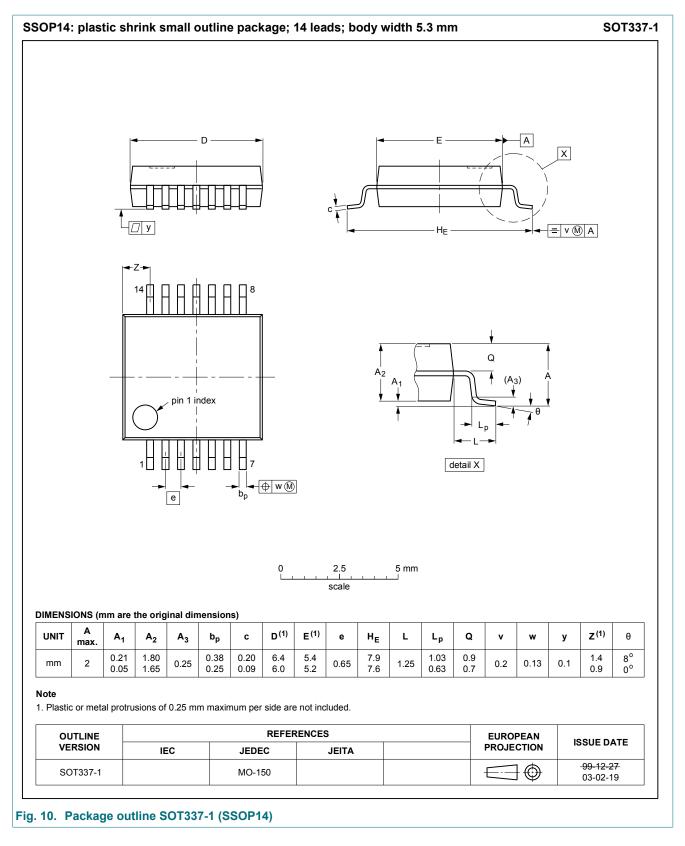


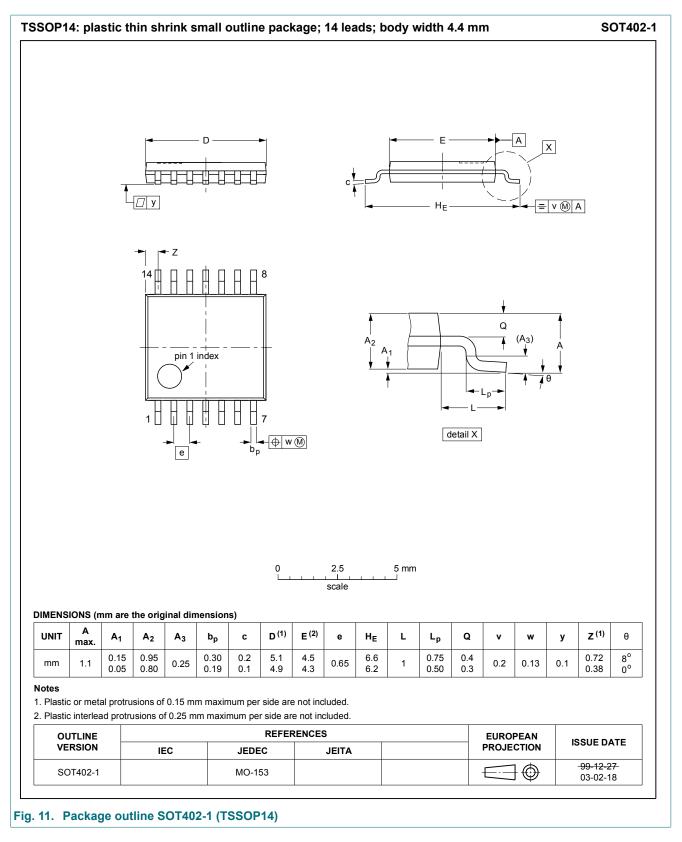
Fig. 9. Package outline SOT108-1 (SO14)

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74HC_HCT20

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12. Abbreviations

Description
Complementary Metal Oxide Semiconductor
Device Under Test
ElectroStatic Discharge
Human Body Model
Machine Model
Transistor-Transistor Logic

13. Revision history

Table 11. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT20 v.5	20190327	Product data sheet	-	74HC_HCT20 v.4		
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Type number 74HCT20PW (SOT402-1/TSSOP14) removed. 					
74HC_HCT20 v.4	20151118	Product data sheet	-	74HC_HCT20 v.3		
Modifications:	Type numbers 74HC20N and 74HCT20N (SOT27-1) removed.					
74HC_HCT20 v.3	20120903	Product data sheet	-	74HC_HCT20_CNV v.2		
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 					
74HC_HCT20_CNV v.2	19970828	Product specification	-	74HC_HCT20_1		

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
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